

# System Photoelectric Smoke Detector

## Description

The CS235 System Smoke Detector is a photo electric type with a pulsed infrared LED as the light source and a silicon photodiode as the light detector. The CS235 IC, along with passive external components, controls the system timing and signal processing.

Low average current is attained by pulsing the system once every 10 seconds for 20 milliseconds. Bias is applied to the signal processing circuitry for this time interval. During the second half of the pulse, the last 10 milliseconds, the IR LED is pulsed and the unit samples for an alarm level smoke condition. After the first alarm level signal the sample rate increases to a two second interval. After three consecutive alarm level samples the logic drives the output latch signalling the system panel.

The signal processing circuit blocks

are amplifiers A1 and A2, synchronous detector, voltage comparator and the decode counter. The voltage gain of A2 and the comparator reference voltage are set by external resistors.

Additional on-chip features include an  $I_{CC}$  current limiter. The current limiter eliminates power-on false alarming.

The oscillator controls the IR LED excitation frequency and provides drive to the synchronous detector. The synchronous detection method has very high noise rejection performance

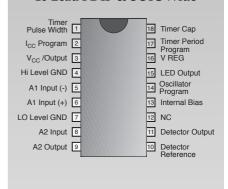
The internal latch is capable of sinking 100 milliamps maximum and will clamp the  $V_{CC}$  pin to 5 volts when tripped. The latch current is determined by an external resistor typically located in the master panel and is reset by temporary removal of detector power.

#### **Features**

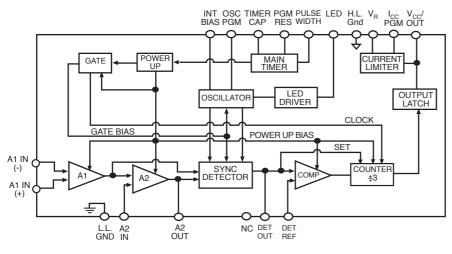
- Synchronous Detection for High Noise Immunity
- Pulsed Operation for Low Average Current Drain
- System Gain Externally Set
- System Sensitivity Externally Adjustable
  - System Operation Monitored by Means of External Red LED

## **Package Options**

18 Lead PDIP & SOIC Wide



### Block Diagram





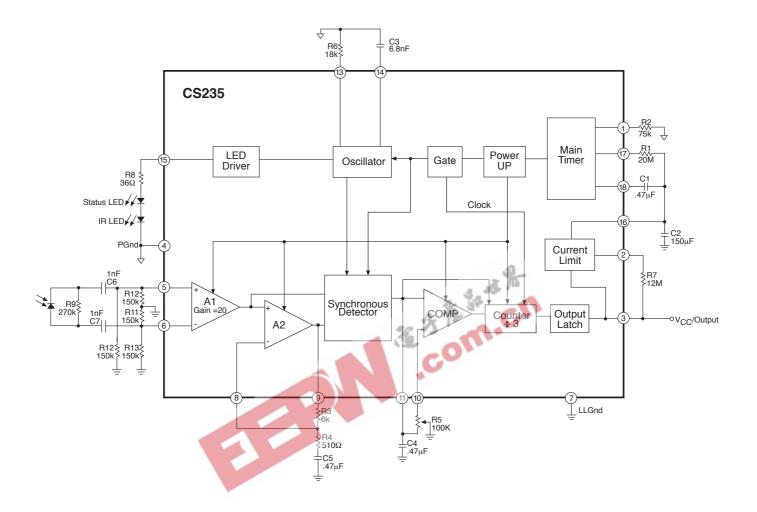
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## Absolute Maximum Ratings

Lead Temperature Soldering	
Wave Solder (through hole styles only)	10 sec. max, 260°C peak
Reflow (SMD styles only)	60 sec. max above 183°C, 230°C peak
Storage Temperature Range	-65°C to 150°C

	ectrical Characteristics: $T_A = 25$ °C, unlo	ess otherwis	e stated.		
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNI
Absolute Maximum Voltage			38	V	
Output Latch Current	-			100	mA
Operation Temperature Range, $T_A$				70	°C
24V System (C2 = 100 μF, R7	= 12 MΩ)				
Operating Voltage	(pin 3)	13.8	22.5	35	V
Average Supply Current	V (pin 3) = 22.5V		35	60	μΑ
Peak Supply Current	V (pin 3) = 22.5V )(non "speed up")			100	μΑ
Peak Supply Current	V (pin 16) = 12V )("speed up")	38	150	350	μΑ
Regulator Voltage	(pin 16)	12.8	-	15.7	V
12V System (C2 = 150μF, R7	= 12ΜΩ)	12.8			
Operating Voltage	(pin 3)	8.7	12		V
Average Supply Current	V (pin 3) = 12V			60	μΑ
Peak Supply Current	V (pin 3) = 12V (non "speed up")			100	μA
Peak Supply Current	oly Current V (pin 16) = 8V ("speed up" mode)			350	μΑ
Regulator Voltage	(pin 16) (V pin $3 = 12V$ )		11.85		V
Oscillator					
Output Frequency	$R6 = 18k\Omega$ , $C3 = .0068\mu$ F	2.1	3.3	4.4	kH
Sink Current	(pin 14)	16	26	35	μΑ
Source Current	(pin 14)	19	26	32	μΑ
High Trip Point Voltage	(pin 14)	1.8	1.9	2.2	V
Low Trip Point Voltage	(pin 14)	1.2	1.4	1.5	V
LED Drive (Detector LED ar	nd Status LED)				
Source Current (pin 15)	R8=36Ω				
Detector LED	V IR LED = 1.156V	20	30	40	mΑ
Status LED (alarm)	V S tatus LED = 1.99V	10			mA
Regulator Voltage (pin 15)	$I_{SOURCE} = 30 \text{mA}$	3.7	4.4	5.2	V
Amplifier A1					
Fixed Gain			26		dB
Input Current B <sub>1</sub>	(pin 5)		500	1000	nA
•					
Input Current B <sub>2</sub>	(pin 6)		500	1000	nA

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNI
Amplifier A2					
DC Output (pin 9)	$R3 = 6k\Omega$ , $R4 = 510\Omega$ , $C5 = .47\mu$ F		2.5		V
Input Bias Current (pin 8)	(Externally adjusted gain with R3 and R4. Unity DC gain)			250	nA
Voltage gain @ 3.5kHz	(Externally adjusted gain with R3 and R4. Unity DC gain)		21.6		dB
Detector and Reference Outp	out (C4 = 47uF)				
Reference Resistance		13	19	25	kΩ
Reference Voltage	(pin 10)	1.8	3.6	5.5	V
Detector Output Resistance		10	15	20	kΩ
Detector Output Voltage	(pin 11) (No signal, and at 2X time Constant)	1.4	2.8	4.3	V
Main Timer (R1 = $20M\Omega$ , R2	= $75k\Omega$ , C1 = .47μF) Standby Mode (pin 1)	8	10	12	Sec
Power Up Pulse Period	J 1				
Power Up Pulse Period Power Up Pulse Period	Speed Up Mode (pin 1)	1.5	2	2.5	Sec
Power Up Pulse Period Power Up Pulse Width	Speed Up Mode (pin 1) (pin 1)	1.5	2 20	2.5	Sec ms
Power Up Pulse Period	Speed Up Mode (pin 1) (pin 1) Power up pulse width 12	1.5	2 20 10	2.5	
Power Up Pulse Period Power Up Pulse Width	Speed Up Mode (pin 1) (pin 1) Power up pulse width 12 V (pin 16) = 16V	1,5	2 20 10 460	2.5	ms
Power Up Pulse Period Power Up Pulse Width Gate Pulse Width Sink Current (pin 18) Source Current (pin 18)	Speed Up Mode (pin 1) (pin 1)  Power up pulse width 12 V (pin 16) = 16V V (pin 16) = 16V	8 1.5 415 -220	2 20 10 460 -235		ms ms
Power Up Pulse Period Power Up Pulse Width Gate Pulse Width Sink Current (pin 18) Source Current (pin 18)  Output Circuit		415 -220 4.4	2 20 10 460 -235	505	ms ms nA
Power Up Pulse Period Power Up Pulse Width Gate Pulse Width Sink Current (pin 18) Source Current (pin 18)	Speed Up Mode (pin 1) (pin 1)  Power up pulse width 12  V (pin 16) = 16V  V (pin 16) = 16V  (pin 3) I <sub>SUPPLY</sub> = 100mA  V (pin 3) = 38V, V (pins 2, 16) = 0V			505 -250	ms ms nA μA
Power Up Pulse Period Power Up Pulse Width Gate Pulse Width Sink Current (pin 18) Source Current (pin 18)  Output Circuit Output Latch Voltage	(pin 3) I <sub>SUPPLY</sub> = 100mA		5.2	505 -250	ms ms nA µA
Power Up Pulse Period Power Up Pulse Width Gate Pulse Width Sink Current (pin 18) Source Current (pin 18)  Output Circuit Output Latch Voltage Leakage Current	(pin 3) I <sub>SUPPLY</sub> = 100mA		5.2	505 -250	ms ms nA µA

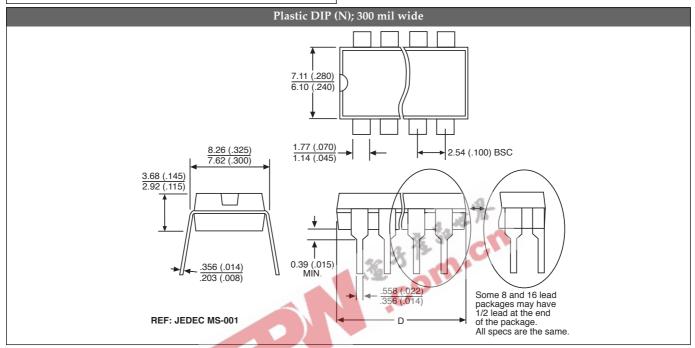


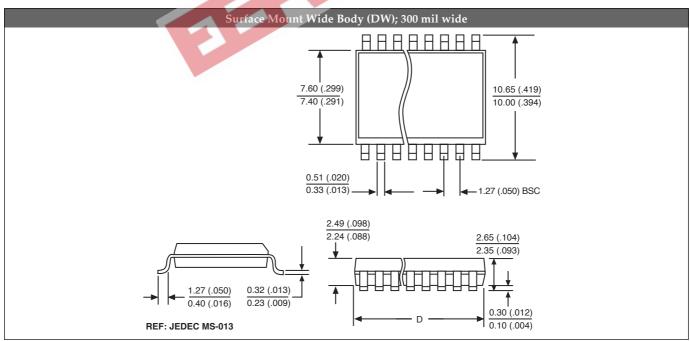
#### Package Specification

#### PACKAGE DIMENSIONS IN mm (INCHES)

			D		
Lead Count	Metric		English		
	Max	Min	Max	Min	
18L PDIP	23.37	22.35	.920	.880	
18L SO Wide	11.75	11.35	.463	.447	

PACKAGE THERMAL DATA				
Therma	l Data	18L SO Wide	18L PDIP	
$R_{\Theta JC}$	typ	21	29	°C/W
$R_{\Theta JA}$	typ	100	65	°C/W





Ordering Information		
Part Number	Description	
CS235GDW18	18L SO	
CS235GDWR18	18L SO (tape & reel)	
CS235GN18	18L PDIP	

Cherry Semiconductor Corporation reserves the right to make changes to the specifications without notice. Please contact Cherry Semiconductor Corporation for the latest available information.